FAIRCHILD SEMICONDUCTOR TM

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MC78MXX/LM78MXX

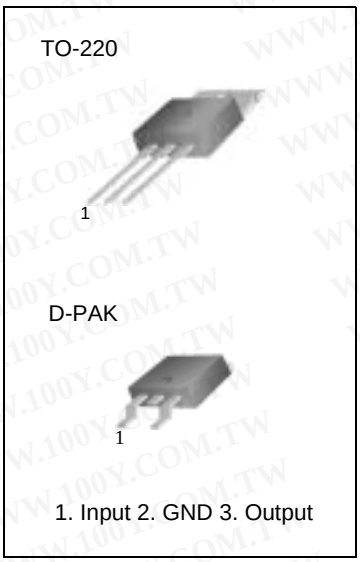
3-terminal 0.5A positive voltage regulator

Features

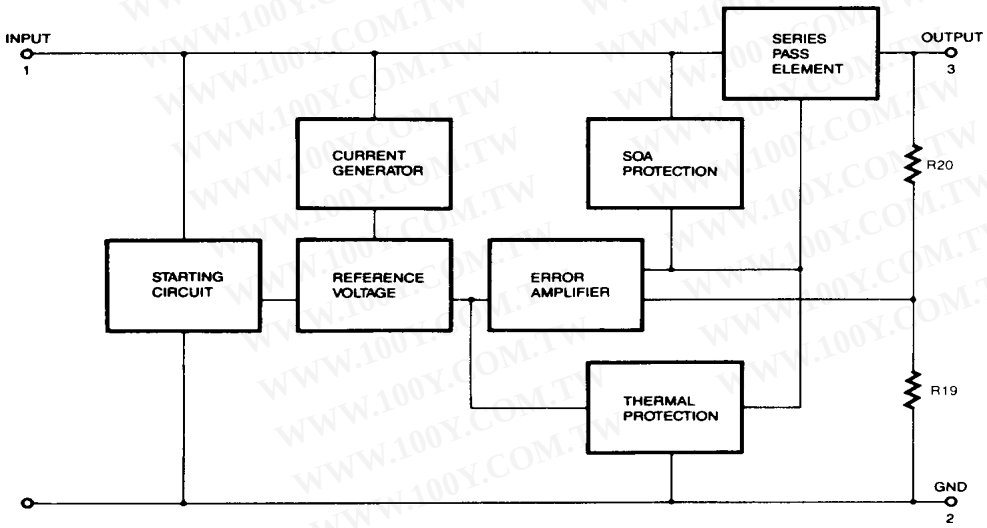
- Output Current up to 0.5A
- Output Voltages of 5, 6, 8, 10, 12, 15, 18, 20, 24V
- Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating area (SOA)Protection

Description

The MC78MXX/LM78MXX series of three-terminal positive regulators are available in the TO-220/D-PAK package with several fixed output voltages making it useful in a wide range of applications.



Internal Block Digram



Rev. 5.0

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V_O = 5V to 18V) (for V_O = 24V)	V_I V_I	35 40	V V
Thermal Resistance Junction-Cases	$R_{\theta JC}$	5	°C/W
Thermal Resistance Junction-Air (TO-220 Package)	$R_{\theta JA}$	65	°C/W
Operating Temperature Range MC78MXX/LM78MXX	T_{OPR}	0~ + 125	°C
Storage Temperature Range	T_{STG}	-65~ + 150	°C

Electrical Characteristics (MC78M05/LM78M05)

(Refer to the test circuits, $0 \leq T_J \leq +125°C$, I_O=350mA, V_I=10V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25°C		4.8	5	5.2	V
		I_O = 5 to 350mA V_I= 7 to 20V		4.75	5	5.25	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 7 to 25V	-	-	100	mV
			V_I = 8 to 25V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	100	mV
		I_O = 5mA to 200mA, T_J =+25 °C		-	-	50	
Quiescent Current	I_Q	T_J=+25°C		-	4.0	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 8 to 25V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	–0.5	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	40	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 8 to 18V		62	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J=+25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J =+25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant junction temperature. Change in V_o due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M06)

(Refer to the test circuits, $0 \le T_J \le +125°C$, I_O=350mA, V_I =11V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	TJ=+25°C		5.75	6	6.25	V
		I_O = 5 to 350mA V_I= 8 to 21V		5.7	6	6.3	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 8 to 25V	-	-	100	mV
			V_I = 9 to 25V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	120	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	60	
Quiescent Current	I_Q	T_J=+25°C		-	4.0	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 9 to 25V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	– 0.5	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	45	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 9 to 19V		59	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J= +25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J =+25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M08)

(Refer to the test circuits, $0 \le T_J \le +125°C$, I_O=350mA, V_I=14V, unless otherwise specified, C_I =0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25 °C		7.7	8	8.3	V
		I_O = 5 to 350mA V_I= 10.5 to 23V		7.6	8	8.4	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 10.5 to 25V	-	-	100	mV
			V_I = 11 to 25V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	160	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	80	
Quiescent Current	I_Q	T_J=+25°C		-	4.0	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 10.5 to 25V		-	-	0.8	
Output Voltage Drift	RR	I_O = 5mA T_J = 0 to +125°C		-	–0.5	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	52	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 9 to 19V		56	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J =+25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J =+25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M12)

(Refer to the test circuits, $0 \le T_J \le 125°C$, I_O=350mA, V_I =19V, unless otherwise specified, C_I =0.33µF, C_O =0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25°C		11.5	12	12.5	V
		I_O = 5 to 350mA V_I= 14.5 to 27V		11.5	12	12.6	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 14.5 to 30V	-	-	100	mV
			V_I = 16 to 30V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	240	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	120	
Quiescent Current	I_Q	T_J=+25°C		-	4.1	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 14.5 to 30V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	– 0.5	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	75	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 15 to 25V		55		-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J= +25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J = +25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M15)

(Refer to the test circuits, $0 \leq T_J \leq +125°C$, I_O=350mA, V_I =23V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25°C		14.4	15	15.6	V
		I_O = 5 to 350mA V_I= 17.5 to 30V		14.25	15	15.75	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 17.5 to 30V	-	-	100	mV
			V_I = 20 to 30V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	300	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	150	
Quiescent Current	I_Q	T_J=+25°C		-	4.1	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 17.5 to 30V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	– 1	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	100	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 18.5 to 28.5V		54	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J= +25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J = + 25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M18)

(Refer to the test circuits, $0 \le T_J \le +125°C$, I_O=350mA, V_I =26V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25°C		17.3	18	18.7	V
		I_O = 5 to 350mA V_I= 20.5 to 33V		17.1	18	18.9	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 21 to 33V	-	-	100	mV
			V_I = 24 to 33V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	360	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	180	
Quiescent Current	I_Q	T_J =+25°C		-	4.2	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 21 to 33V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O =5mAT_J =0 to 125°C		-	–1.1	-	mV/°C
Output Noise Voltage	V_N	f=10Hz to 100KHz		-	100	-	µV
Ripple Rejection	RR	f=120Hz, I_O=300mA , V_I=22 to 32V		53	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O=500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J =+25°C, V_I=35V		-	300	-	mA
Peak Current	I_{PK}	T_J =+25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M20)

(Refer to the test circuits, $0 \le T_J \le +125°C$, I_O=350mA, V_I =29V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J= +25°C		19.2	20	20.8	V
		I_O = 5 to 350mA V_I= 23 to 35V		19	20	21	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 23 to 35V	-	-	100	mV
			V_I = 24 to 35V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	400	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	200	
Quiescent Current	I_Q	T_J=+25°C		-	4.2	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 23 to 35V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	–1.1	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	110	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 24 to 34V		53	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J = +25°C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J = +25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M24)

(Refer to the test circuits, $0 \le T_J \le +125°C$, I_O=350mA, V_I=33V, unless otherwise specified, C_I = 0.33µF, C_O=0.1µF)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	T_J=+25°C		23	24	25	V
		I_O = 5 to 350mA V_I= 27 to 38V		22.8	24	25.2	
Line Regulation	ΔV_O	I_O = 200mA T_J =+25°C	V_I= 27 to 38V	-	-	100	mV
			V_I = 28 to 38V	-	-	50	
Load Regulation	ΔV_O	I_O = 5mA to 0.5A, T_J =+25°C		-	-	480	mV
		I_O = 5mA to 200mA, T_J =+25°C		-	-	240	
Quiescent Current	I_Q	T_J=+25°C		-	4.2	6	mA
Quiescent Current Change	ΔI_Q	I_O = 5mA to 350mA		-	-	0.5	mA
		I_O = 200mA V_I = 27 to 38V		-	-	0.8	
Output Voltage Drift	$\Delta V/\Delta T$	I_O = 5mA T_J = 0 to +125°C		-	– 1.2	-	mV/°C
Output Noise Voltage	V_N	f = 10Hz to 100KHz		-	170	-	µV
Ripple Rejection	RR	f = 120Hz, I_O = 300mA V_I = 28 to 38V		50	-	-	dB
Dropout Voltage	V_D	T_J =+25°C, I_O = 500mA		-	2	-	V
Short Circuit Current	I_{SC}	T_J= +25 °C, V_I= 35V		-	300	-	mA
Peak Current	I_{PK}	T_J =+25°C		-	700	-	mA

Notes:

*Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Applications

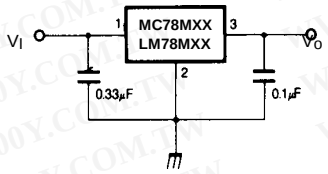


Figure 1. Fixed Output Regulator

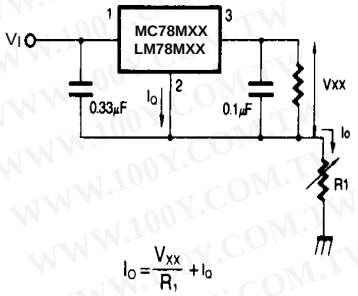


Figure 2. Constant Current Regulator

Notes:

1. To specify an output voltage, substitute voltage value for "XX"
2. Although no output capacitor is needed for stability, it does improve transient response.
3. Required if regulator is located an appreciable distance from power Supply filter

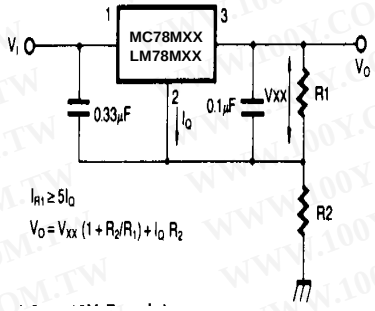


Figure 3. Circuit for Increasing Output Voltage

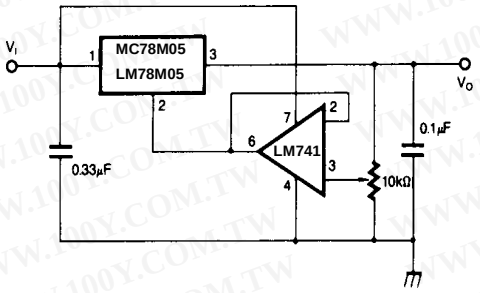
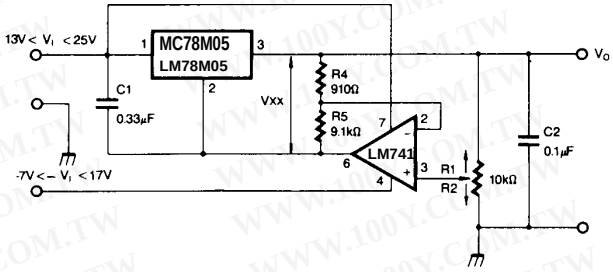


Figure 4. Adjustable Output Regulator (7 to 30V)



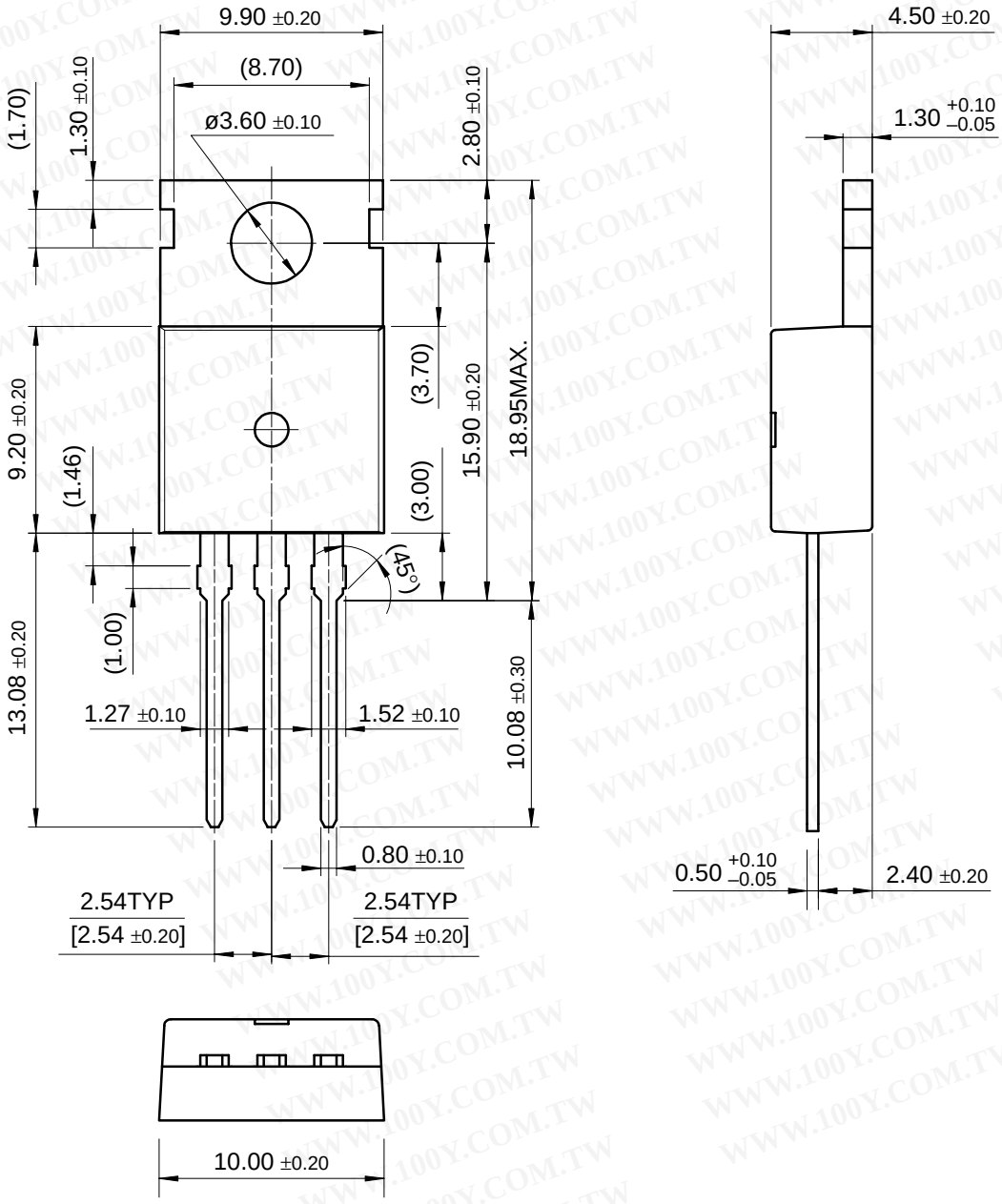
$$V_O = V_{XX} \frac{R_4}{R_1}$$

Figure 5. 0.5 to 10V Regulator

Mechanical Dimensions

Package

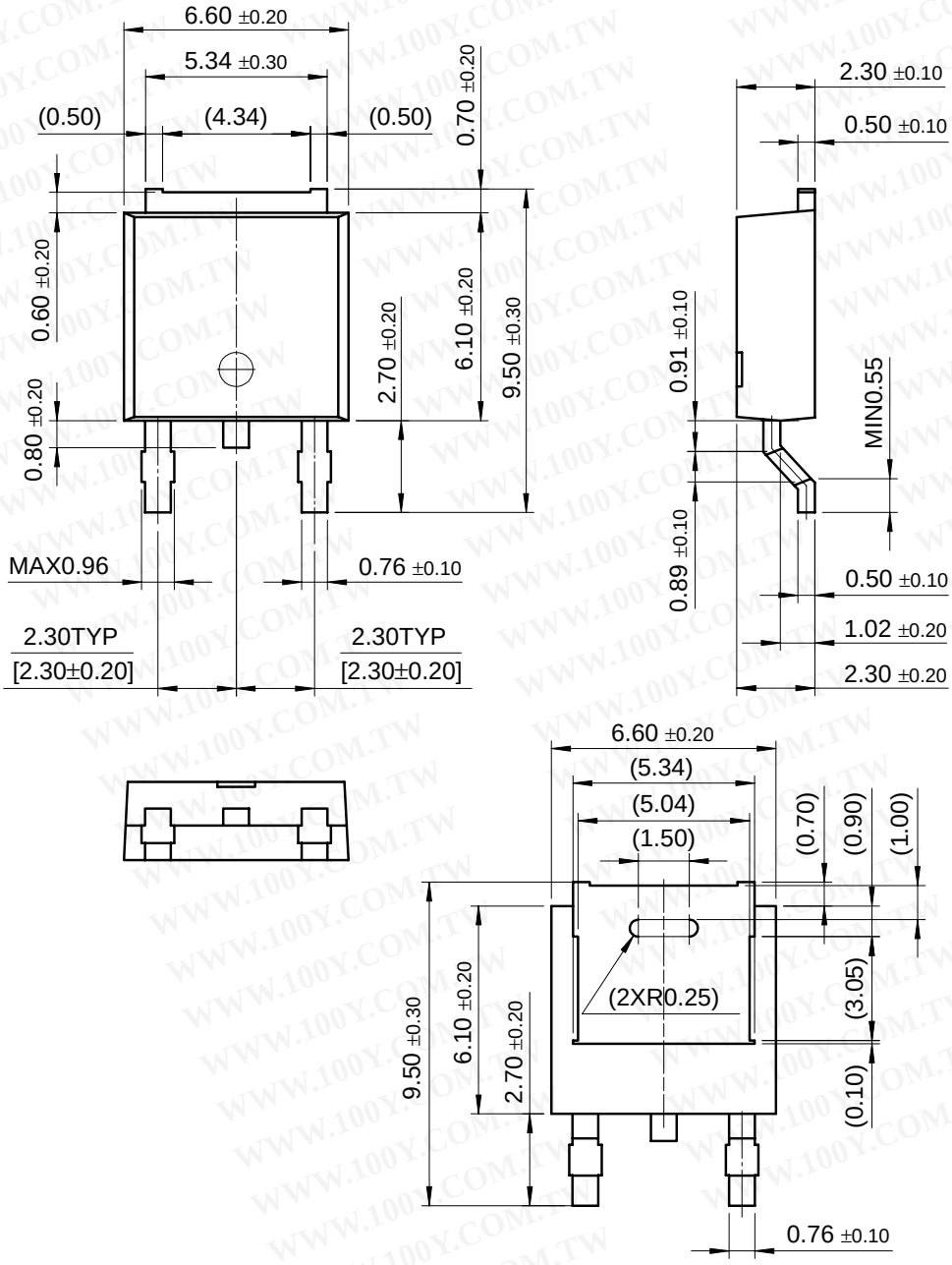
TO-220



Mechanical Dimensions (Continued)

Package

D-PAK



Ordering Information

Product Number	Package	Operating Temperature
LM78M05CT	TO-220	0 ~ + 125°C

Product Number	Package	Operating Temperature
MC78M05CT	TO-220	0 ~ + 125°C
MC78M06CT		
MC78M08CT		
MC78M12CT		
MC78M15CT		
MC78M18CT		
MC78M20CT		
MC78M24CT		
MC78M05CDT	D-PAK	
MC78M08CDT		
MC78M12CDT		

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